## **AMENDMENTS TO THE CLAIMS**

The following listing of claims will replace all prior versions and listings of claims in the application.

## **LISTING OF CLAIMS**

- 1. (cancelled).
- 2. (cancelled).
- 3. (currently amended) An organic bistable memory device comprising an organic bistable element and a limiter, wherein

the organic bistable element comprising comprises an organic thin film having a single layer structure interposed between a first electrode and a second electrode, and

the limiter limits current, which flows in either a positive bias side or a negative bias side to a given value in writing information into the organic bistable element,

the organic thin film consisting essentially of an organic compound represented by formula (I):

$$\begin{array}{c}
R^{1} \\
R^{3} \\
H
\end{array}$$
(I)

wherein, in R<sup>1</sup>, R<sup>2</sup>, and R<sup>3</sup>,

one or two of them each independently represent an electron-donating group selected from the group consisting of –H, -NH<sub>2</sub> -NHR, -NR<sub>2</sub>. -SR, -X, -CX<sub>3</sub>, -OH, -OCH<sub>3</sub>, -OR and -R wherein R represents a straight chain or branched chain alkyl group having 1 to 24 carbon atoms in which one or at least two methylene groups in the alkyl group are optionally substituted by a substituent of -0-, -S-, -CO-, -CHW-, wherein W represents -F -Cl -Br -l -CN or -CF<sub>3</sub>, -CH=CH-, or -CEC-, provided that a plurality of said substituents are not adjacent to each other, and X represents -F. -Cl -Br, or -l and

the remaining group or groups of  $R^1$ ,  $R^2$ , and  $R^3$  each independently represent an electron-receiving group selected from the group consisting of -CN, - [[N0<sub>2</sub>]] NO<sub>2</sub>, -COR. - COOH, -COOR and -SO<sub>3</sub>H.

- 4. (cancelled).
- 5. (cancelled).

6. (original) The organic bistable memory device according to Claim 3, further comprising a substrate and either the first electrode or the second electrode is stacked in contact with a top of the substrate.